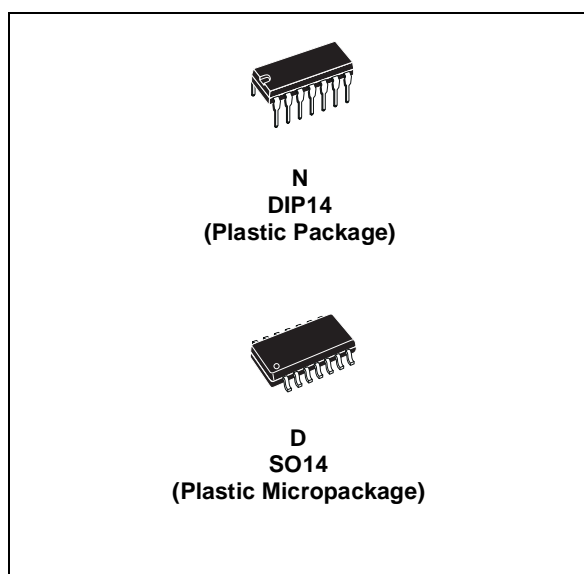




WIDE BANDWIDTH QUAD J-FET OPERATIONAL AMPLIFIERS

- LOW POWER CONSUMPTION
- WIDE COMMON-MODE (UP TO V_{CC}^+) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : 16V/ μ s (typ)



DESCRIPTION

These circuits are high speed J-FET input quad operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

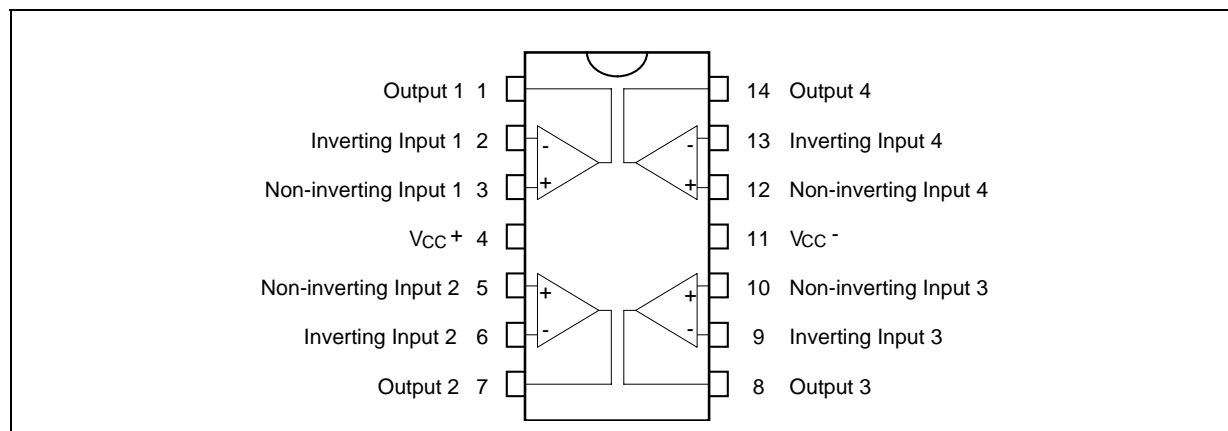
ORDER CODE

Part Number	Temperature Range	Package	
		N	D
LF147	-55°C, +125°C	•	•
LF247	-40°C, +105°C	•	•
LF347	0°C, +70°C	•	•

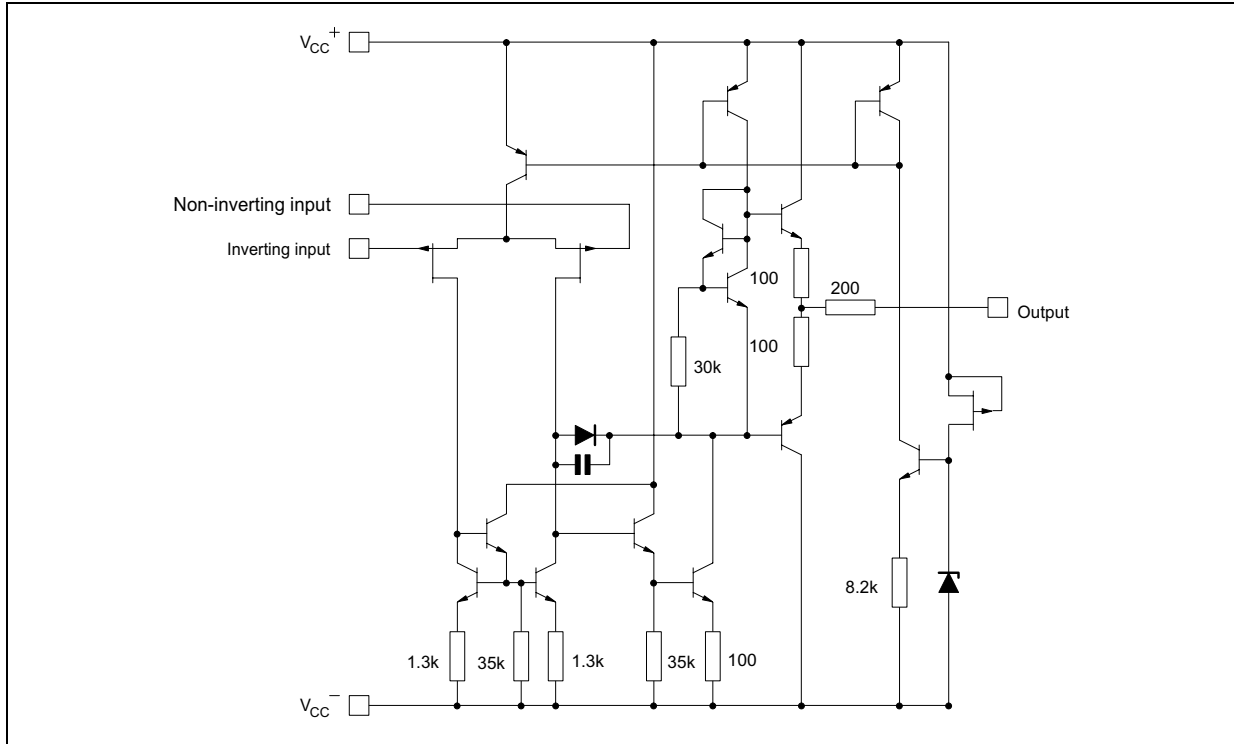
Example : LF347IN

N = Dual in Line Package (DIP)
D = Small Outline Package (SO) - also available in Tape & Reel (DT)

PIN CONNECTIONS (top view)



SCHEMATIC DIAGRAM (each amplifier)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	LF147	LF247	LF347	Unit
V_{CC}	Supply voltage - note ¹⁾	± 18			V
V_i	Input Voltage - note ²⁾	± 15			V
V_{id}	Differential Input Voltage - note ³⁾	± 30			V
P_{tot}	Power Dissipation	680			mW
	Output Short-circuit Duration - note ⁴⁾	Infinite			
T_{oper}	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T_{stg}	Storage Temperature Range	-65 to +150			°C

1. All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC+} and V_{CC-} .
2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded

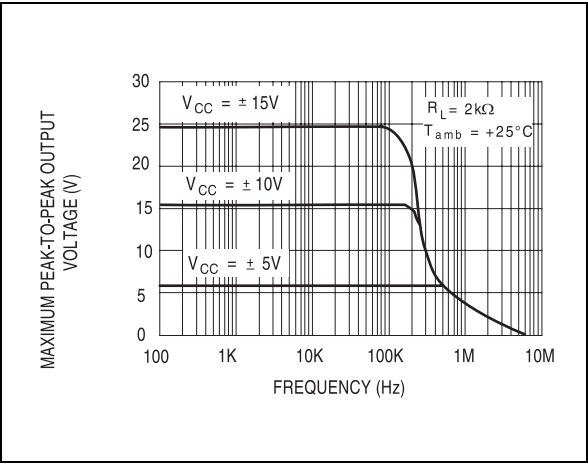
ELECTRICAL CHARACTERISTICS

$V_{CC} = \pm 15V$, $T_{amb} = +25^{\circ}C$ (unless otherwise specified)

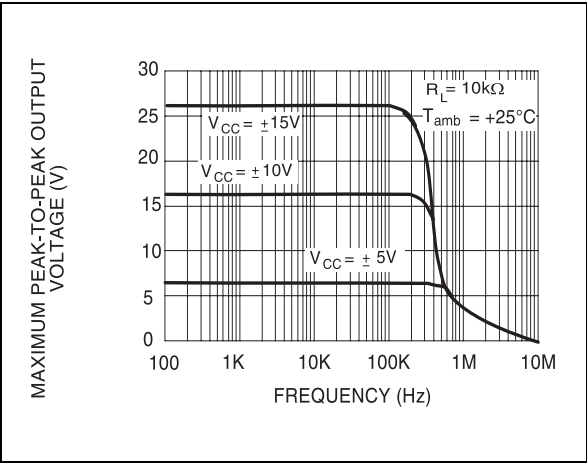
Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ($R_S = 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		3	10 13	mV
DV_{io}	Input Offset Voltage Drift		10		$\mu V/^{\circ}C$
I_{io}	Input Offset Current - note 1) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		5	100 4	pA nA
I_{ib}	Input Bias Current - note 1 $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	200 20	pA nA
A_{vd}	Large Signal Voltage Gain ($R_L = 2k\Omega$, $V_O = \pm 10V$), $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	50 25	200		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S = 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	80 80	86		dB
I_{CC}	Supply Current, Per Amp, no Load $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		1.4	2.7 2.7	mA
V_{icm}	Input Common Mode Voltage Range	± 11	+15 -12		V
CMR	Common Mode Rejection Ratio ($R_S = 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	70 70	86		dB
I_{OS}	Output Short-Circuit Current $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	10 10	40	60 60	mA
$\pm V_{opp}$	Output Voltage Swing $T_{amb} = 25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 2k\Omega$ $R_L = 10k\Omega$ $R_L = 2k\Omega$ $R_L = 10k\Omega$	10 12 10 12	12 13.5		V
SR	Slew Rate $V_i = 10V$, $R_L = 2k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, unity gain	12	16		V/ μs
t_r	Rise Time $V_i = 20mV$, $R_L = 2k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, unity gain		0.1		μs
K_{ov}	Overshoot $V_i = 20mV$, $R_L = 2k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, unity gain		10		%
GBP	Gain Bandwidth Product $f = 100kHz$, $T_{amb} = 25^{\circ}C$, $V_{in} = 10mV$, $R_L = 2k\Omega$, $C_L = 100pF$	2.5	4		MHz
R_i	Input Resistance		10^{12}		Ω
THD	Total Harmonic Distortion $f = 1kHz$, $A_v = 20dB$, $R_L = 2k\Omega$, $C_L = 100pF$ $T_{amb} = 25^{\circ}C$, $V_O = 2V_{pp}$		0.01		%
e_n	Equivalent Input Noise Voltage ($R_S = 100\Omega$, $f = 1KHz$)		15		$\frac{nV}{\sqrt{Hz}}$
ϕ_m	Phase Margin		45		Degrees
V_{O1}/V_{O2}	Channel Separation ($A_v = 100$)		120		dB

1. The input bias currents are junction leakage currents which approximately double for every $10^{\circ}C$ increase in the junction temperature.

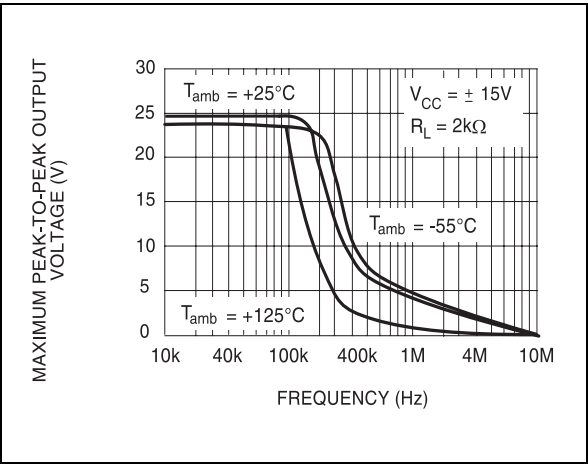
**MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE versus FREQUENCY**



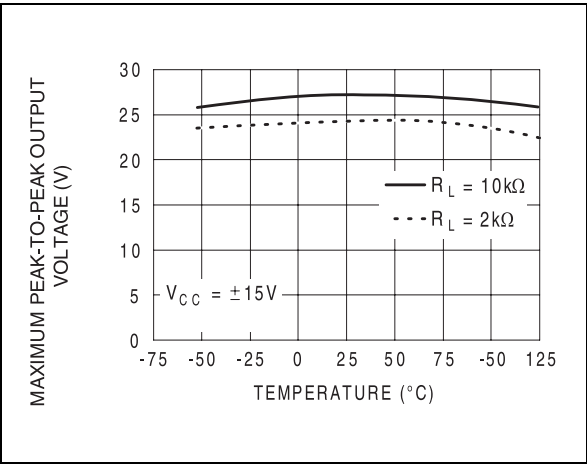
**MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE versus FREQUENCY**



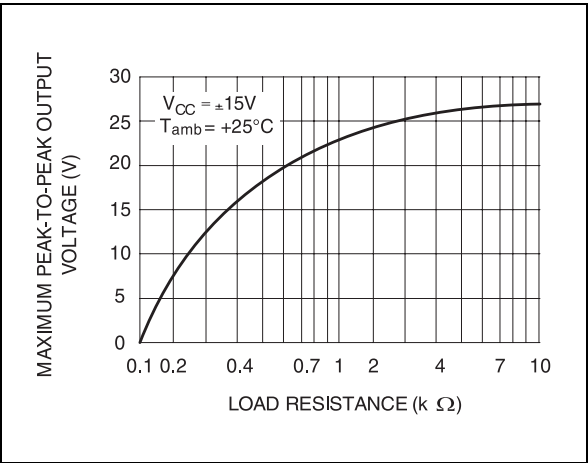
**MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE versus FREQUENCY**



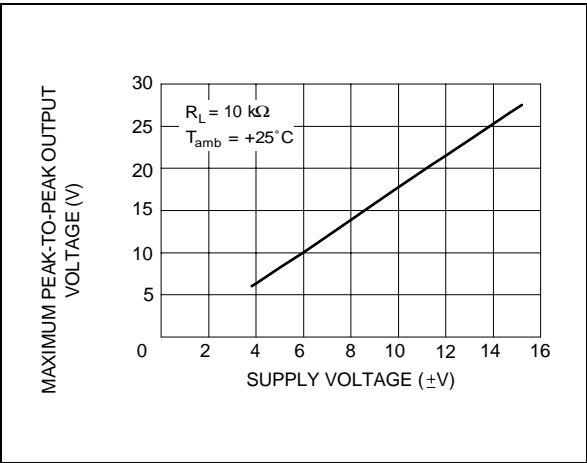
**MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE versus FREE AIR TEMP.**



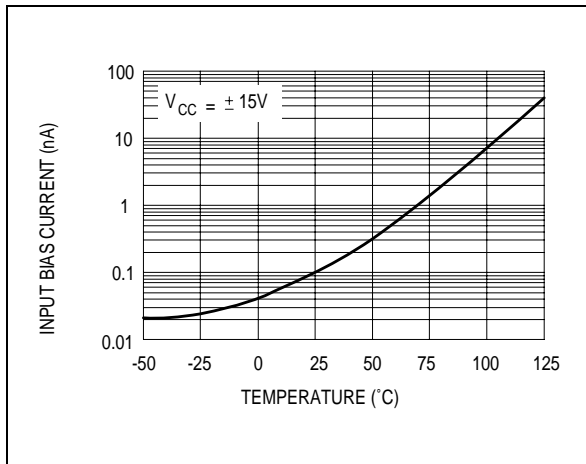
**MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE versus LOAD RESISTANCE**



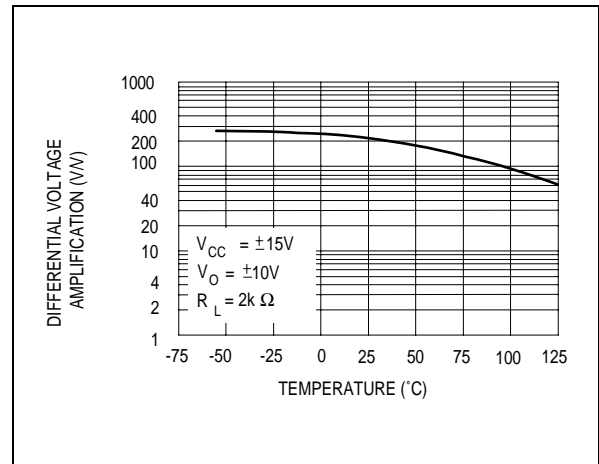
**MAXIMUM PEAK-TO-PEAK OUTPUT
VOLTAGE versus SUPPLY VOLTAGE**



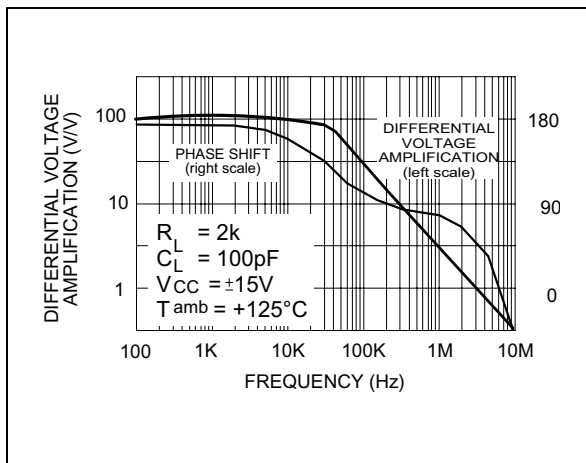
INPUT BIAS CURRENT versus FREE AIR TEMPERATURE



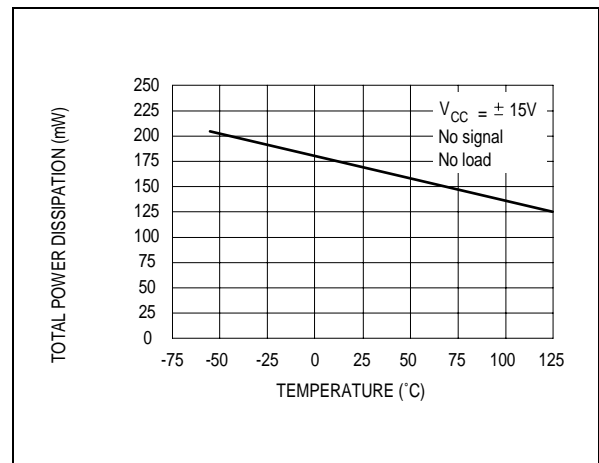
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



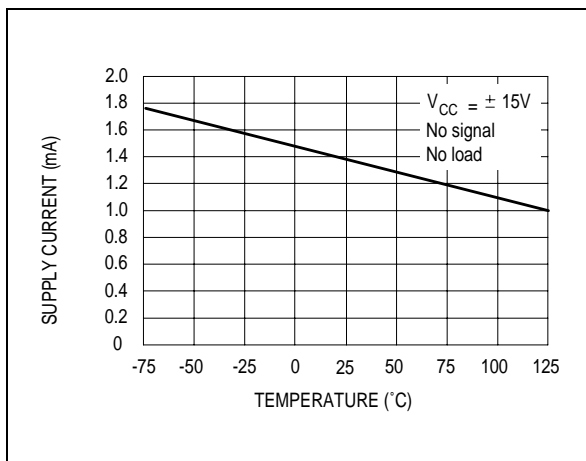
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



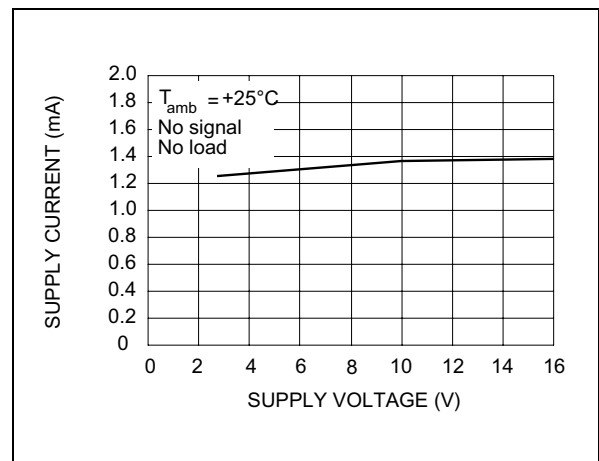
TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE



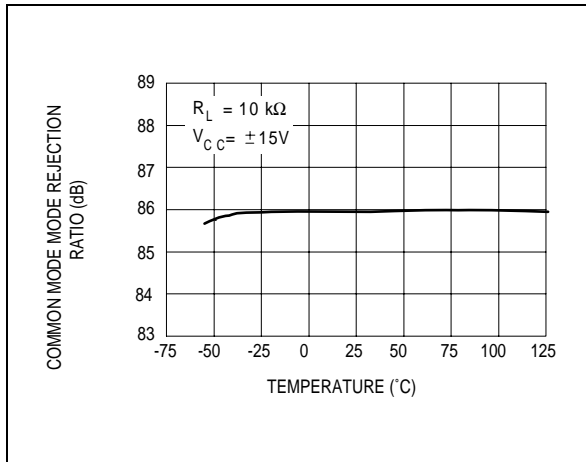
SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE



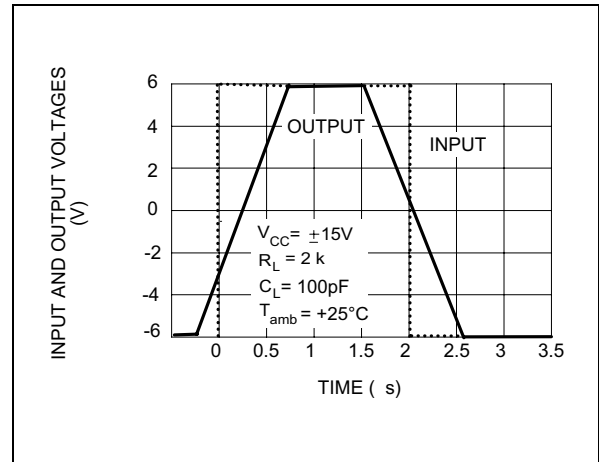
COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE



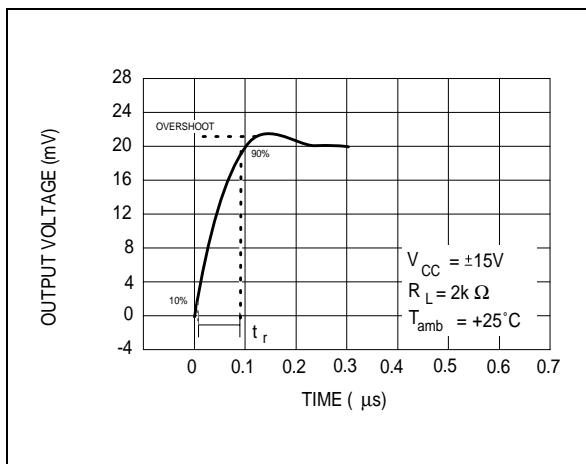
**COMMON MODE REJECTION RATIO versus
FREE AIR TEMPERATURE**



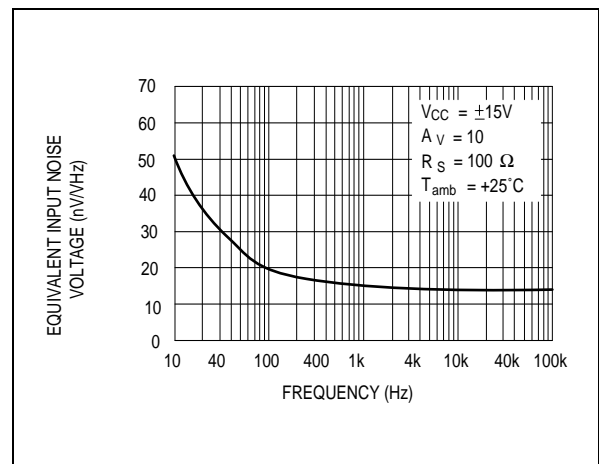
**VOLTAGE FOLLOWER LARGE SIGNAL PULSE
RESPONSE**



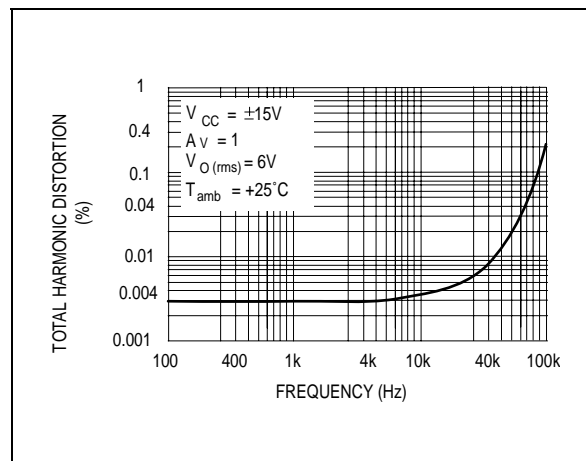
OUTPUT VOLTAGE versus ELAPSED TIME



**EQUIVALENT INPUT NOISE VOLTAGE versus
FREQUENCY**



TOTAL HARMONIC DISTORTION versus FREQUENCY



PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

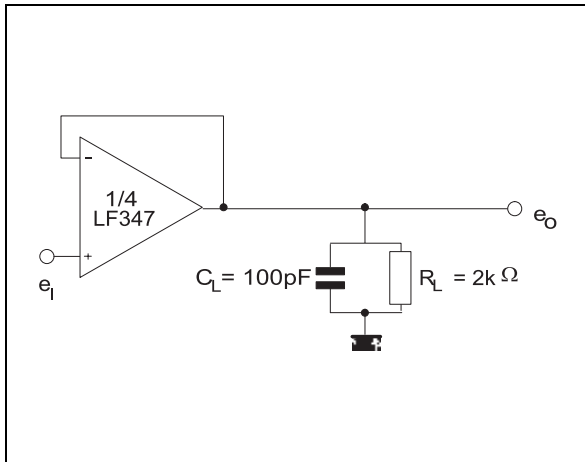
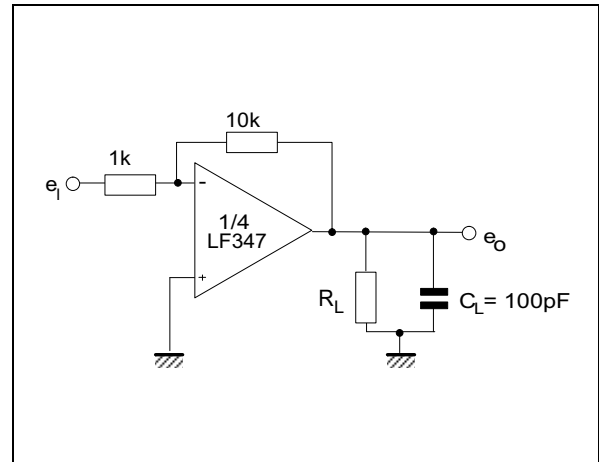
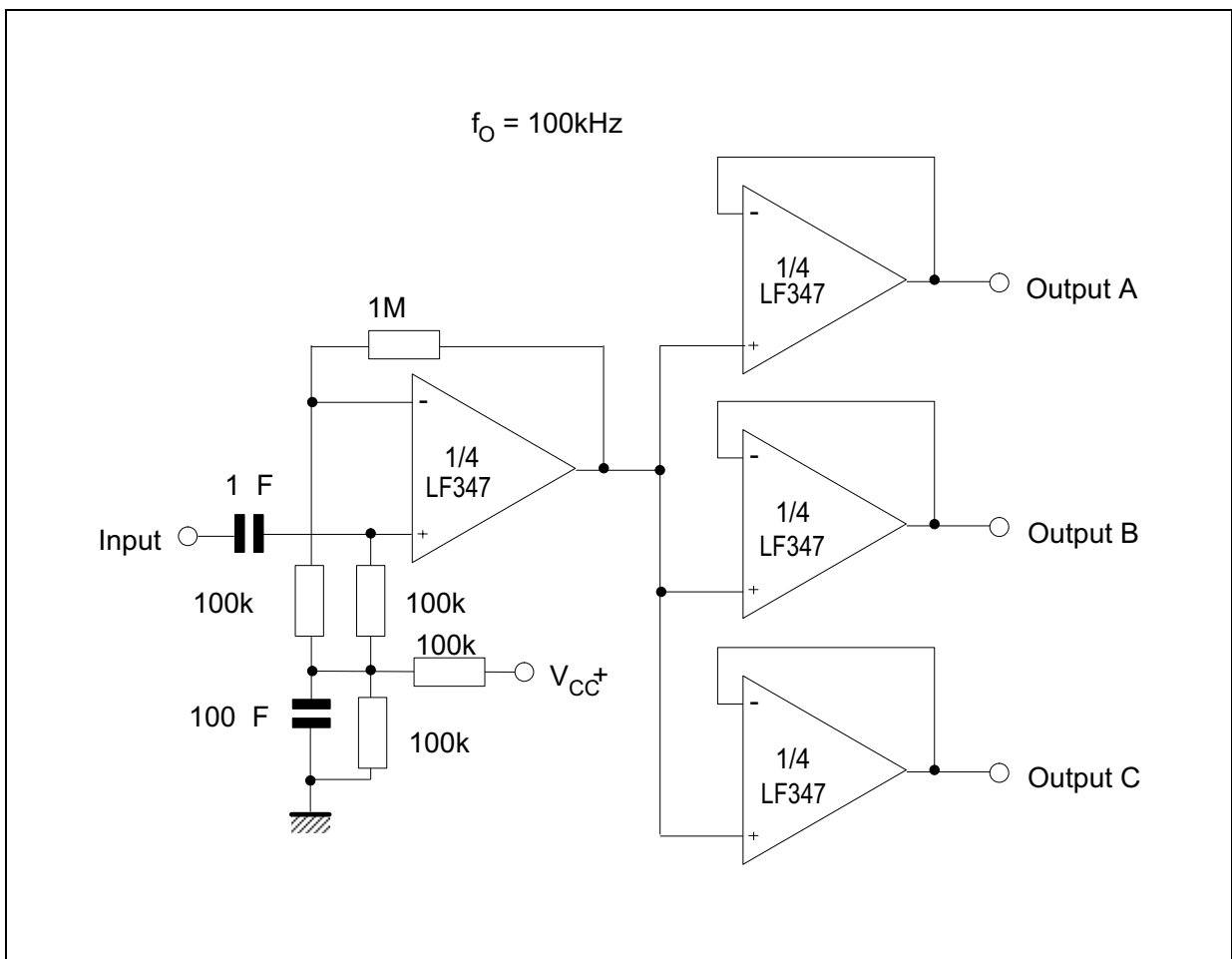


Figure 2 : Gain-of-10 Inverting Amplifier



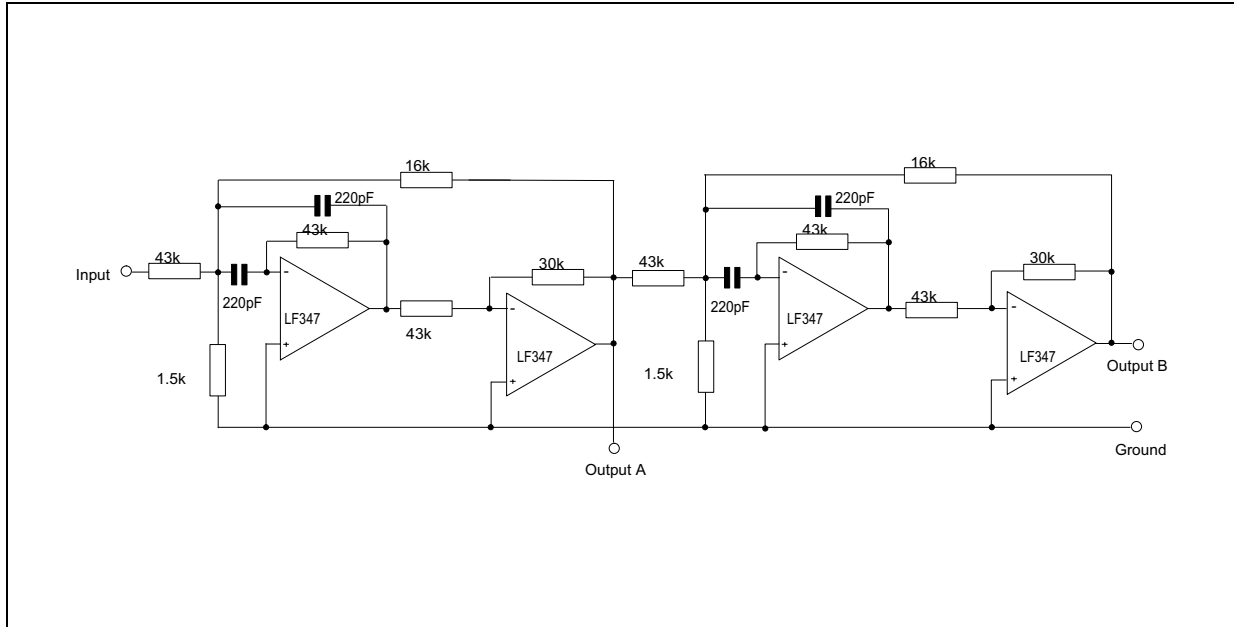
TYPICAL APPLICATIONS

AUDIO DISTRIBUTOR AMPLIFIER

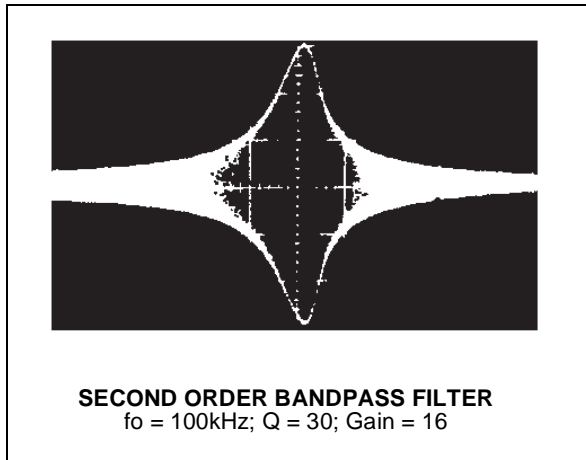


TYPICAL APPLICATIONS (continued)

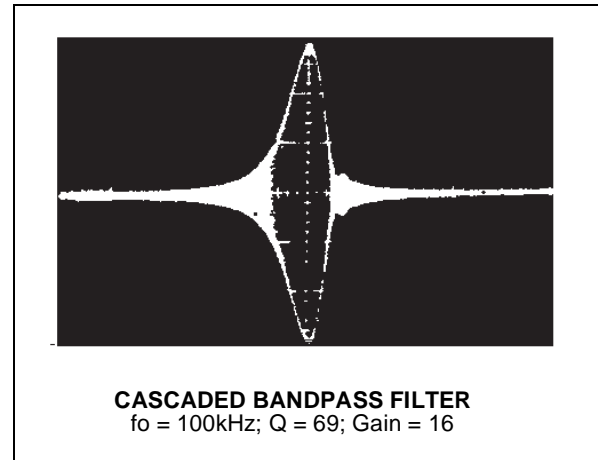
POSITIVE FEEDBACK BANDPASS FILTER



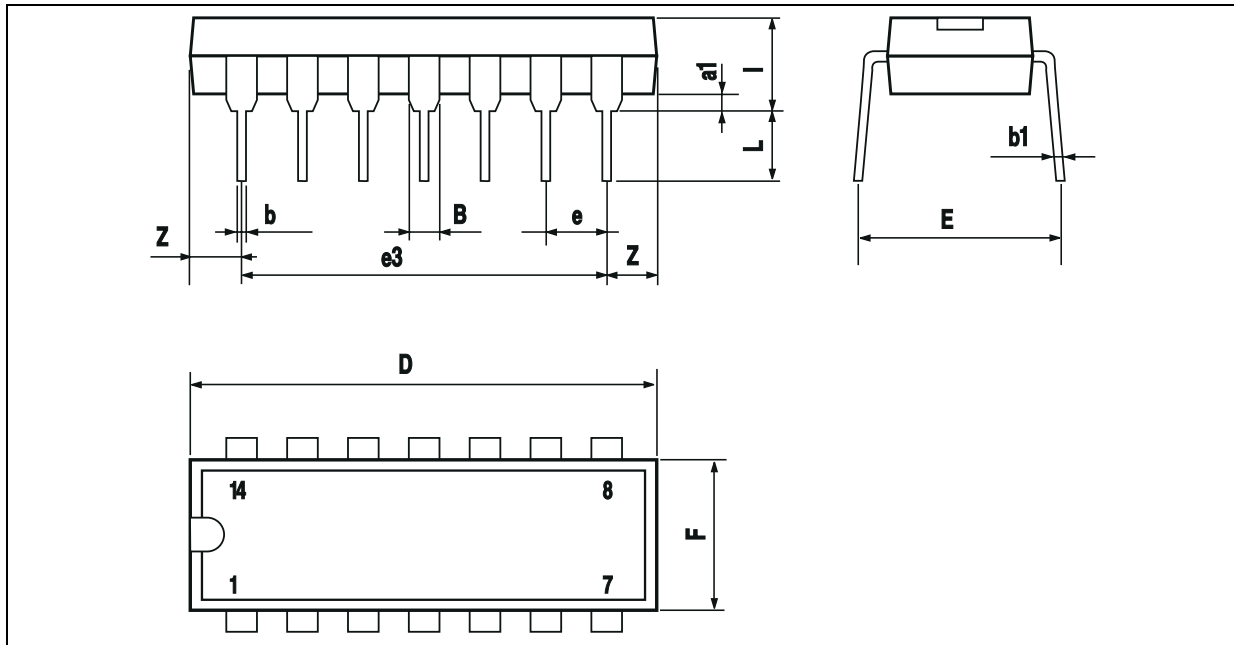
OUTPUT A



OUTPUT B



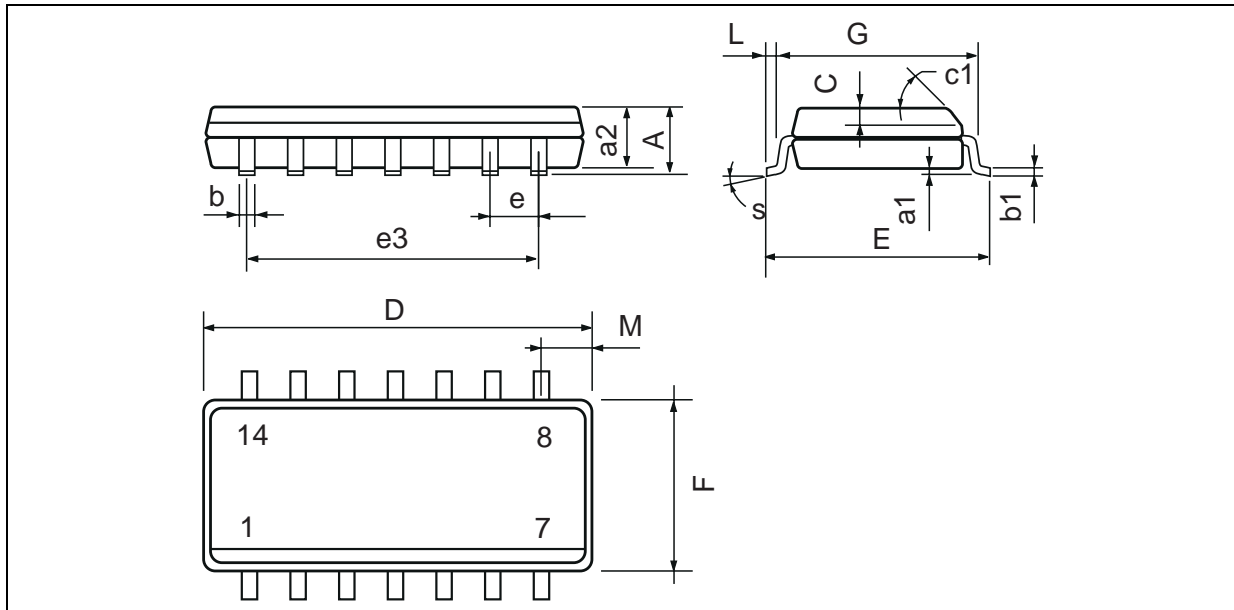
PACKAGE MECHANICAL DATA
14 PINS - PLASTIC DIP



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA

14 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D (1)	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F (1)	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

Note : (1) D and F do not include mold flash or protrusions - Mold flash or protrusions shall not exceed 0.15mm (.066 inc) ONLY FOR DATA BOOK.

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